

TELEDYNE SOLID STATE

MILITARY POWER FET AC/DC SOLID STATE RELAY

OPTICALLY ISOLATED
UP TO 1.3 AMP AT 25°C

SERIES
685
686
690
691

RADIATION
TESTED
SP57/110

FEATURES

- DC or AC/DC units available
- Surge blocking voltage of 80 volts peak (per MIL-704)
- Power FET output
- Fast switching speed
- Low on-resistance (0.3 ohms typ.)
- Virtually no offset voltage
- Opto isolation up to 1200 volts
- Input CMOS or TTL compatible
- 3.8 to 32.0 volt input range (Table 1)
- Constant current input in TTL mode
- Schmitt trigger input in buffered mode at 50 microamps
- Built and tested to MIL-R-28750 utilizing the test methods of MIL-STD-883C
- Radiation hardening levels: contact factory

APPLICATIONS

- Low level switching applications
- Isolated line drivers
- Current loop switches
- Servo and synchro resolver control
- Load control from microcomputer I/O ports
- Data coupler
- General purpose analog and transducer signal switching in military/aerospace applications
- Telecommunications

DESCRIPTION

These all solid state relays utilize the latest power FET output technology to minimize on-state resistance and bipolar offset voltages normally associated with solid state relay outputs. The input and output are optically isolated to protect delicate input logic circuits from output voltage transients. The input is buffered to enable the relay to be driven directly by CMOS logic gates or standard interface circuitry. A Schmitt trigger at the input significantly increases noise margin when using the relay in the CMOS input mode. This prevents false triggering in noisy environments. State-of-the-art construction techniques maximizes MTBF and minimizes package size.

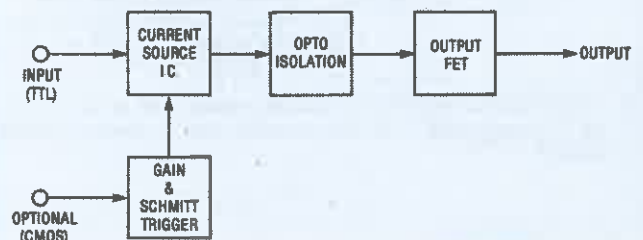
The 685 and 686 are housed in metal DIP packages which maximize heat dissipation.

The 690 and 691 are housed in low profile Centrigrid® packages which conserve space in high density packaging applications.

PART NUMBERING AND GENERAL SPECIFICATIONS

Teledyne Part No.	Maximum Continuous Operating Output Voltage	Maximum Load Current (25°C)
690-1	60 Volts DC	0.56 DC Amps
690-2	60 Volts DC	1.00 DC Amps
691-1	±60 Volts Peak	0.40 Amp (RMS)
691-2	±60 Volts Peak	0.70 Amp (RMS)
685-1	60 Volts DC	0.75 DC Amps
685-2	60 Volts DC	1.35 DC Amps
686-1	±60 Volts Peak	0.54 Amp (RMS)
686-2	±60 Volts Peak	0.95 Amp (RMS)

BLOCK DIAGRAM



INPUT (CONTROL) CHARACTERISTICS When used in 5 terminal configuration (CMOS) See Fig. 3

	MIN.	TYP.	MAX.	UNITS
Input Current @ 5 VDC			250	μA
Control Voltage Range	2.5		18	VDC
Bias Supply Range V _c	3.8		32	VDC Table 1
Bias Current		13	16	mA
Turn-Off Minimum (For guaranteed off)		2.5	2.8	VDC
Turn-On Maximum (For guaranteed on)	0.5			VDC
Total Schmitt Hysteresis		1.8		VDC

INPUT (CONTROL) CHARACTERISTICS When used in 4 terminal configuration (TTL) See Fig. 2

	MIN.	TYP.	MAX.	UNITS
Input Current		13	16	mA
Control Voltage Range	3.8		32	VDC Table 1
Turn-Off Maximum (For guaranteed off)			1.5	VDC
Turn-On Minimum (For guaranteed on)	3.8			VDC

SERIES 685/690

ELECTRICAL CHARACTERISTICS AT 25°C

		690-1	685-1	690-2	685-2	691-1	686-1	691-2	686-2	Units	
Maximum Continuous Operating Output Voltage		60 Volts DC				±60 Volts Peak				Volts (DC or Peak)	
Maximum Load Current At 25°C		0.56	0.75	1.0	1.35	0.40	0.54	0.70	0.95	Amps (DC or RMS)	
ON Resistance	Typ.	0.60		0.30		1.2		0.60		Ohms	
	Max.	0.90		0.35		1.6		0.70			
Maximum Output Capacitance		160		400		80		200		pf at 25V 1 MHz	
Maximum Input-Output Capacitance		5									pf at 25V 1 KHz
Typical Thermal Resistance	θJA	150	90	120	70	150	90	120	70	°C/Watt	
	θJC	40	30	30	25	40	30	30	25		
t _r * (Typical Rise Time)		0.8		1.5		1.2		2.0		msec	
t _{dON} * (Typical On Delay)		0.7		0.8		0.8		2.2		msec	
t _f * (Typical Fall Time)		0.4		0.6		0.6		0.6		msec	
t _{dOFF} * (Typical Off Delay)		1.8		2.0		2.4		2.5		msec	
Maximum Surge Voltage Note 5 (Transient Blocking) 2 sec max.		80									Volt (DC or Peak)
Leakage Current at 60 Volts, 25°C		10									μA
Dielectric Strength (Input-Output)		1000	1200	1000	1200	1000	1200	1000	1200	VAC RMS 60Hz Sine Wave	
Isolation (Input to Case at 500 Volts)		10*									Ohms
Current Surge		200% of maximum load current at 25°C for 1 sec duration 10% duty cycle									

NOTES:

- Used in the 5 terminal CMOS compatible configuration, the relays provide inversion such that when the control voltage is 0.5 VDC or less, the relay's output will be guaranteed "on." When the control voltage is 2.8 VDC or more the relay's output will be guaranteed "off."
- In the 4 terminal TTL configuration the relays are non-inverting. When the TTL driving gate is sinking the drive current the relay output will be on.
- All power FET relays may drive loads connected to either positive or negative referenced power supply lines. (Source or sink modes)
- For on state resistance at temperatures other than 25°C, use the following equation —

$$R = R_{25} \times e^{0.006 \times \Delta T}$$

where R₂₅ = resistance at 25°C from table
 R = resistance at new temperature
 ΔT = new temperature - 25°C
 e = 2.7182818

- If 600V transient capability is required, a zener diode across the output is recommended. If an internal zener diode is required, consult factory.

ENVIRONMENTAL SPECIFICATIONS*

Temperature (Ambient Operating)	-55°C to Maximum Per Thermal Derating Curve
Temperature (Ambient Storage)	-55°C to 125°C
Vibration	100g, 10 to 3000 Hz
Shock	1500g, 0.5 msec
Acceleration	5000g

*For higher environmental requirements, contact factory.

CONTROL INPUT RESISTANCE REQUIREMENTS

Vc Range	3.8-6V	6.0-10V	10-14V	14-18V	18-22V	22-26V	26-32V
Rs Ohms		300	620	910	1200	1500	2000
Power Rating Watts	Not Required	¼	¼	½	½	½	1

TABLE 1

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9